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MM3Z2V4ST1 SERIES

Zener Voltage Regulators

200 mW SOD-323 Surface Mount **Tight Tolerance Portfolio**

This series of Zener diodes is packaged in a SOD-323 surface mount package that has a power dissipation of 200 mW. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand-held portables, and high density PC boards.

Specification Features:

- Standard Zener Breakdown Voltage Range -2.4 V to 12 V
- Steady State Power Rating of 200 mW
- Small Body Outline Dimensions: 0.067" x 0.049" (1.7 mm x 1.25 mm)
- Low Body Height: 0.035" (0.9 mm)
- Package Weight: 4.507 mg/unit
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- Tight Tolerance V_Z
- Pb–Free Packages are Available

Mechanical Characteristics:

CASE: Void-free, transfer-molded plastic FINISH: All external surfaces are corrosion resistant MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES: 260°C for 10 Seconds LEADS: Plated with Pb–Sn or Sn only (Pb–Free) POLARITY: Cathode indicated by polarity band FLAMMABILITY RATING: UL 94 V-0 **MOUNTING POSITION: Any**

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) @ T _A = 25°C Derate above 25°C	P _D	200 1.5	mW mW/°C
Thermal Resistance from Junction-to-Ambient	R_{\thetaJA}	635	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 Minimum Pad



ON Semiconductor[®]

http://onsemi.com





M = Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
MM3ZxxxST1	SOD-323	3000/Tape & Reel
MM3ZxxxST3	SOD-323	10,000/Tape & Reel
MM3ZxxxST1G	SOD-323 (Pb-Free)	3000/Tape & Reel
MM3ZxxxST3G	SOD-323 (Pb-Free)	10,000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA for all types)

Symbol	Parameter					
Vz	Reverse Zener Voltage @ I _{ZT}					
I _{ZT}	Reverse Current					
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}					
Ι _{ΖΚ}	Reverse Current					
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}					
Ι _R	Reverse Leakage Current @ V _R					
V _R	Reverse Voltage					
١ _F	Forward Current					
V _F	Forward Voltage @ I _F					
ΘV_Z	Maximum Temperature Coefficient of V_Z					
С	Max. Capacitance $@V_R = 0$ and f = 1 MHz					



ELECTRICAL CHARACTERISTICS (V_F = 0.9 Max @ I_F = 10 mA for all types)

		Test	Zener Vo	Itage VZ	Z _{ZK} I _Z = 0.5	Z _{ZT} I _Z = IZT @ 10%	Ma IR @	ax 》VR	d _{VZ} /dt @ I _{ZT1}	(mV/k) = 5 mA	C pF Max @
Device	Device Marking	Current Izt mA	Min	Max	mA Ω Max	Mod Ω Max	μΑ	v	Min	Max	V _R = 0 f = 1 MHz
MM3Z2V4ST1	T2	5.0	2.43	2.63	1000	100	120	1.0	-3.5	0	450
MM3Z2V7ST1	Т3	5.0	2.67	2.91	1000	100	100	1.0	-3.5	0	450
MM3Z3V3ST1	T5	5.0	3.32	3.53	1000	95	5.0	1.0	-3.5	0	450
MM3Z3V3TT1, G	ТΧ	5.0	3.19	3.41	100	95	5.0	1.0	-3.5	0	450
MM3Z3V6ST1, G	Т6	5.0	3.60	3.85	1000	90	5.0	1.0	-3.5	0	450
MM3Z3V9ST1, G	T7	5.0	3.89	4.16	1000	90	3.0	1.0	-3.5	-2.5	450
MM3Z4V3ST1	Т8	5.0	4.17	4.43	1000	90	3.0	1.0	-3.5	0	450
MM3Z4V7ST1, G	Т9	5.0	4.55	4.75	800	80	3.0	2.0	-3.5	0.2	260
MM3Z5V1ST1	TA	5.0	4.98	5.2	500	60	2.0	2.0	-2.7	1.2	225
MM3Z5V6ST1	TC	5.0	5.49	5.73	200	40	1.0	2.0	-2.0	2.5	200
MM3Z6V2ST1	TE	5.0	6.06	6.33	100	10	3.0	4.0	0.4	3.7	185
MM3Z6V8ST1	TF	5.0	6.65	6.93	160	15	2.0	4.0	1.2	4.5	155
MM3Z7V5ST1	TG	5.0	7.28	7.6	160	15	1.0	5.0	2.5	5.3	140
MM3Z8V2ST1	TH	5.0	8.02	8.36	160	15	0.7	5.0	3.2	6.2	1358
MM3Z9V1ST1	ТК	5.0	8.85	9.23	160	15	0.5	6.0	3.8	7.0	130
MM3Z10VST1	WB	5.0	9.80	10.20	160	15	0.5	6.0	4.5	8.0	130
MM3Z11VST1	WC	5.0	10.78	11.22	160	15	0.5	7.0	5.4	9.0	130
MM3Z12VST1	TN	5.0	11.74	12.24	80	25	0.1	8.0	6.0	10	130
MM3Z15VST1*	WF	5.0	14.7	15.3	80	30	0.05	10.5	9.2	13	110

*Product preview – parts available upon request.

MM3Z2V4ST1 SERIES

Typical Characteristics



MM3Z2V4ST1 SERIES

PACKAGE DIMENSIONS

SOD-323 CASE 477-02 ISSUE D





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS. 3. LEAD THICKNESS SPECIFIED PER L/F
- 3. LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS
- DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIN	IETERS	INCHES			
DIM	MIN	MIN MAX MIN I		MAX		
Α	1.60	1.80	0.063	0.071		
В	1.15	1.35	0.045	0.053		
С	0.80	1.00	0.031	0.039		
D	0.25	0.40	0.010	0.016		
E	0.15	REF	0.006	REF		
н	0.00	0.10	0.000	0.004		
J	0.089	0.177	0.0035	0.0070		
к	2.30	2.70	0.091	0.106		
L	0.075		0.003			

STYLE 1: PIN 1. CATHODE 2. ANODE

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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